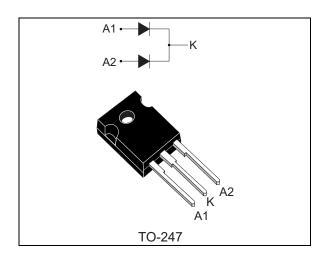
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STTH60SW03C

Turbo 2 ultrafast high voltage rectifier

Datasheet - production data



Features

- Ultrafast switching
- · Low reverse recovery current
- Reduces switching losses
- Low thermal resistance
- ECOPACK®2 compliant component

Description

The STTH60SW03C uses ST Turbo 2 300 V technology. It is especially suited to be used for DC/DC and DC/AC converters in the secondary stage of MIG/MMA/TIG welding machines.

Housed in ST's TO-247, this device offers high power integration for all welding machines and industrial applications.

Table 1. Device summary

Symbol	Value
I _{F(AV)}	2 x 30A
V_{RRM}	300 V
t _{rr} (typ)	20 ns
V _F (typ)	1.05 V
T _j (max)	175 °C

Characteristics STTH60SW03C

1 Characteristics

Table 2. Absolute ratings (limiting values per diode at 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit			
V _{RRM}	Repetitive peak reverse voltage	300	V			
I _{F(RMS)}	Forward rms current	45	Α			
	Average forward current, δ = 0.5 square waveform	T _C = 85 °C	Per diode	30	A	
I _{F(AV)}		T _C = 75 °C	Per device	60		
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms si	nusoidal	200	Α	
T _{stg}	Storage temperature range	-65 to +175	°C			
Tj	Maximum operating junction temperature	175	°C			

Table 3. Thermal parameters

Symbol	Parameter	Value	Unit	
В	Junction to case	Per diode	1.8	
R _{th(j-c)}	Junction to case	Total	1	°C/W
R _{th(c)}	Coupling		0.2	

When diodes 1 and 2 are used simultaneously:

$$T_{j(diode1)} = P_{(diode1)} \times R_{th(j-c)}(per diode) + P_{(diode2)} \times R_{th(c)}$$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	\/ -\/			15	μA
'R`	Theverse leakage current	Perse leakage current $T_j = 125 \text{ °C}$ $V_R = V_{RRM}$	VR - VRRM		15	150	μΛ
	$T_j = 25 ^{\circ}\text{C}$ $T_j = 150 ^{\circ}\text{C}$ $T_j = 150 ^{\circ}\text{C}$			1.55			
V _F ⁽²⁾			1.05	1.25	V		
VF.	Forward voltage drop	T _j = 25 °C	——— I⊏ = 60 A			1.85	V
		T _j = 150 °C			1.35	1.6	

^{1.} Pulse test: t_p = 5 ms, δ < 2%

To evaluate the conduction losses use the following equation:

$$P = 0.89 \text{ x } I_{F(AV)} + 0.012 I_{F}^{2}_{(RMS)}$$

^{2.} Pulse test: t_p = 380 μ s, δ < 2%

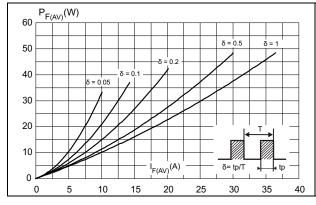
STTH60SW03C Characteristics

Table 5	Pacayary	characteristics	(nor diada)
Table 5.	Recoverv	cnaracteristics	(ber aloae)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
t _{rr}	Reverse recovery time	T _j = 25 °C	$I_F = 1A$, $V_R = 30 V$, $dI_F/dt = -100 A/\mu s$		20	27	ns
I _{RM}	Reverse recovery current				7	9	Α
Q _{rr}	Reverse recovery charge	T _j = 125 °C	$I_F = 30 \text{ A}, V_R = 200 \text{ V},$ $dI_F/dt = -200 \text{ A/}\mu\text{s}$		190		nC
S _{factor}	Softness factor				0.3		
t _{fr}	Forward recovery time	T _i = 25 °C	I _F = 30 A, V _{FR} = 1.6 V,			180	ns
V _{FP}	Forward recovery voltage	1 _j = 25 C	$F/dt = +400 \text{ A/}\mu\text{s}$		3.5	5	V

Figure 1. Average forward power dissipation versus average forward current (per diode)

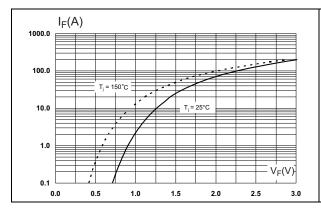
Figure 2. Forward voltage drop versus forward current (typical values, per diode)

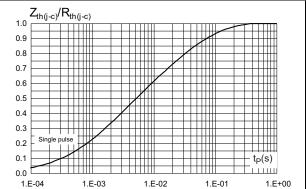


100.0 100.0 10.0

Figure 3. Forward voltage drop versus forward current (maximum values, per diode)

Figure 4. Relative variation of thermal impedance, junction to case, versus pulse duration

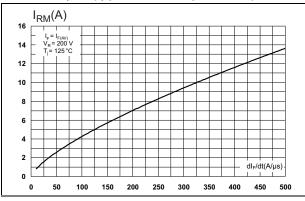




Characteristics STTH60SW03C

Figure 5. Peak reverse recovery current versus dl_F/dt (typical values, per diode)

Figure 6. Reverse recovery time versus dl_F/dt (typical values, per diode)



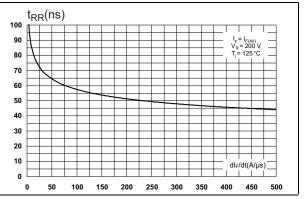
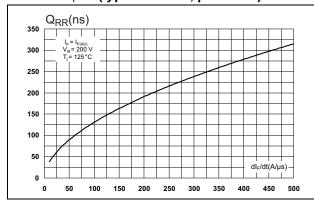


Figure 7. Reverse recovery charges versus dl_F/dt (typical values, per diode)

Figure 8. Reverse recovery softness factor versus dl_F/dt (typical values, per diode)



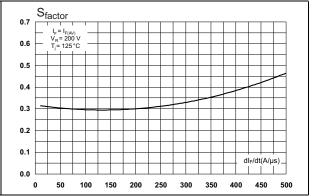
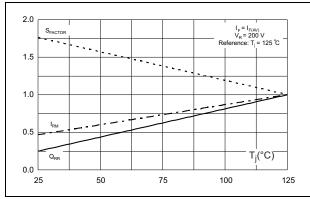
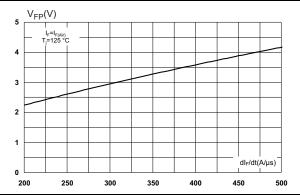


Figure 9. Relative variations of dynamic parameters versus junction temperature

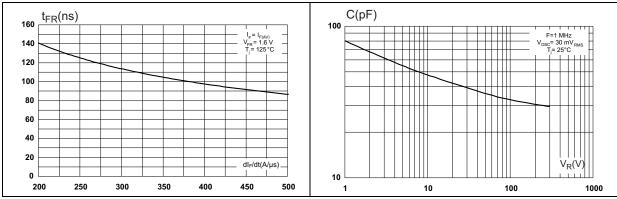
Figure 10. Transient peak forward voltage versus dl_F/dt (typical values, per diode)





STTH60SW03C Characteristics

Figure 11. Forward recovery time versus dl_{\(\pi\)}/dt Figure 12. Junction capacitance versus reverse (typical values, per diode) voltage applied (typical values, per diode)



Package information STTH60SW03C

2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque: TO-247 0.5 to 1.0 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Figure 13. TO-247 dimension definitions

A

Heat-sink plane

D

L2

BACK VIEW

Table 6. TO-247 dimension values

	Dime				mensions		
Ref.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур	Max.	
Α	4.85		5.15	0.191		0.203	
A1	2.20		2.60	0.086		0.102	
b	1.00		1.40	0.039		0.055	
b1	2.00		2.40	0.078		0.094	
b2	3.00		3.40	0.118		0.133	
С	0.40		0.80	0.015		0.031	
D ⁽¹⁾	19.85		20.15	0.781		0.793	
Е	15.45		15.75	0.608		0.620	
е	5.30	5.45	5.60	0.209	0.215	0.220	
L	14.20		14.80	0.559		0.582	
L1	3.70		4.30	0.145		0.169	
L2		18.50 typ.			0.728 typ.		
$\varnothing P^{(2)}$	3.55		3.65	0.139		0.143	
ØR	4.50		5.50	0.177		0.217	
S	5.30	5.50	5.70	0.209	0.216	0.224	

^{1.} Dimension D plus gate protrusion does not exceed 20.5 mm.

^{2.} Resin thickness around the mounting hole is not less than 0.9 mm.

Ordering information STTH60SW03C

3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH60SW03CW	STTH60SW03CW	TO-247	4.46	50	Tube

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
13-Jan-2015	1	First release.

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